

CMOS Digital Integrated Circuits Silicon Monolithic

TC7MBL3125CFT,TC7MBL3126CFT

1. Functional Description

· Low-Voltage, Low-Capacitance Quad Bus Switch

2. General

The TC7MBL3125CFT and TC7MBL3126CFT are a low-voltage/low-capacitance CMOS 4bit Bus Switch. The low on-resistance of the switch allows connections to be made with minimal propagation delay time.

The TC7MBL3125CFT requires the output enable (\overline{OE}) input to be set high to place the output into the high impedance state, whereas the TC7MBL3126CFT requires the output enable (OE) input to be set low to place the output into the high impedance.

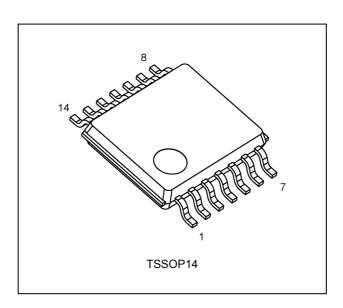
All inputs are equipped with protection circuits against static discharge.

3. Features

- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) Operating voltage: $V_{CC} = 1.65$ to 3.6 V
- (3) ON capacitance: $C_{I/O} = 7.5 \text{ pF Switch On (typ.)} @V_{CC} = 3.0 \text{ V}$
- (4) ON resistance: $R_{ON} = 6.5 \Omega$ (typ.) @ $V_{CC} = 3.0 \text{ V}$, $V_{IS} = 0 \text{ V}$
- (5) ESD performance: $MM \ge \pm 200 \text{ V}$, $HBM \ge \pm 2000 \text{ V}$
- (6) Power-down protection for inputs (OE, OE and I/O)
- (7) Package: TSSOP14

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.

4. Packaging

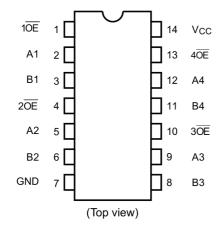


Start of commercial production

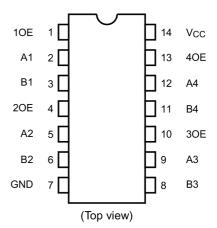


5. Pin Assignment

TC7MBL3125CFT

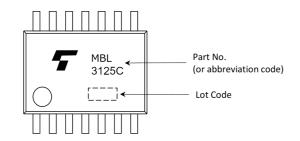


TC7MBL3126CFT

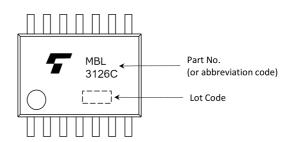


6. Marking

TC7MBL3125CFT

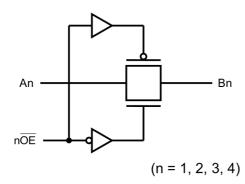


TC7MBL3126CFT

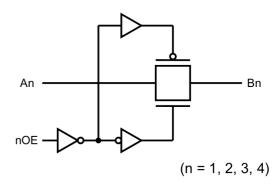


7. System Diagram

TC7MBL3125CFT



TC7MBL3126CFT



8. Truth Table

Inputs OE (TC7MBL3125CFT)	Inputs OE (TC7MBL3126CFT)	Function
L	Н	A port = B port
Н	L	Disconnect



9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}			-0.5 to 4.6	V
Input voltage (OE, OE)	V _{IN}			-0.5 to 4.6	V
Switch I/O voltage	Vs		V _{CC} = 0 V or Switch = Off	-0.5 to 4.6	V
			Switch = On	-0.5 to V _{CC} +0.5	
Clamp diode current	I _{IK}			-50	mA
Switch I/O current	Is			50	mA
Power dissipation	P _D	(Note 1)		180	mW
V _{CC} /ground current	I _{CC} /I _{GND}			±100	mA
Storage temperature	T _{stg}			-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}			1.65 to 3.6	V
Input voltage (OE, OE)	V_{IN}			0 to 3.6	V
Switch I/O voltage	Vs		V _{CC} = 0 V or Switch = Off	0 to 3.6	V
			Switch = On	0 to V _{CC}	
Operating temperature	T _{opr}	(Note 1)		-40 to 125	°C
Input rise time	dt/dv			0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage (OE, OE)	V _{IH}		_	1.65 to 3.6	$0.7 \times V_{CC}$	_	_	V
Low-level input voltage (OE, OE)	V _{IL}			1.65 to 3.6	_	_	0.3 × V _{CC}	V
Input leakage current (OE, OE)	I _{IN}		V _{IN} = 0 to 3.6 V	1.65 to 3.6	_	_	±1.0	μА
Power-OFF leakage current	I _{OFF}		OE , OE, A, B = 0 to 3.6 V	0	_	_	10	μА
Switch OFF-state leakage current	I _{SZ}		$A, B = 0 \text{ V to V}_{CC},$ $\overline{OE} = V_{CC}$ $(TC7MBL3125CFT),$ $OE = GND$ $(TC7MBL3126CFT)$	1.65 to 3.6		_	±1.0	μА
ON-resistance	R _{ON}		V _{IS} = 0 V, I _{IS} = 30 mA	3.0	_	6.5	11	Ω
			V _{IS} = 3.0 V, I _{IS} = 30 mA	3.0	_	11	17	
			V _{IS} = 2.4 V, I _{IS} = 15 mA	3.0	_	13	19	
			V _{IS} = 0 V, I _{IS} = 24 mA	2.3	_	7	11	
			V _{IS} = 2.3 V, I _{IS} = 24 mA	2.3	_	14	21	
			V _{IS} = 2.0 V, I _{IS} = 15 mA	2.3	_	16	23	
			V _{IS} = 0 V, I _{IS} = 4 mA	1.65	_	8	14	
			V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	_	19	27	
Quiescent supply current	Icc		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	3.6	_	_	10	μА

Note 1: All typical values are at $T_a = 25$ °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.



11.2. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
High-level input voltage (OE, OE)	V _{IH}		_	1.65 to 3.6	0.7×V _{CC}	_	V
Low-level input voltage (OE, OE)	V _{IL}		_	1.65 to 3.6	_	0.3×V _{CC}	V
Input leakage current (OE, OE)	I _{IN}		V _{IN} = 0 to 3.6 V	1.65 to 3.6	_	±10.0	μА
Power-OFF leakage current	I _{OFF}		OE, OE, A, B = 0 to 3.6 V	0	_	40	μА
Switch OFF-state leakage current	I _{SZ}		$\begin{array}{l} A, B = 0 \text{ V to V}_{CC}, \\ \overline{OE} = V_{CC} \\ (TC7MBL3125CFT), \\ OE = GND \\ (TC7MBL3126CFT) \end{array}$	1.65 to 3.6		±10.0	μА
ON-resistance	R _{ON}	(Note 1)	V _{IS} = 0 V, I _{IS} = 30 mA	3.0		13	Ω
			V _{IS} = 3.0 V, I _{IS} = 30 mA	3.0		19	
			V _{IS} = 2.4 V, I _{IS} = 15 mA	3.0	_	21	
			V _{IS} = 0 V, I _{IS} = 24 mA	2.3	_	13	
			V _{IS} = 2.3 V, I _{IS} = 24 mA	2.3	_	23	
			V _{IS} = 2.0 V, I _{IS} = 15 mA	2.3	_	25	
			V _{IS} = 0 V, I _{IS} = 4 mA	1.65	_	16	
			V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	_	29	
Quiescent supply current	I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	3.6	_	40	μА

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.

Note 1: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

11.3. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Output enable time	t_{PZL}, t_{PZH}	_{ZL} ,t _{PZH} See Fig. 11.6., 11.7.1,	3.3 ± 0.3		6	ns
		Table 11.6.1	2.5 ± 0.2		7	
			1.8 ± 0.15	_	11	
Output disable time	t _{PLZ} ,t _{PHZ}	See Fig. 11.6., 11.7.1,	3.3 ± 0.3	_	6	ns
		Table 11.6.1	2.5 ± 0.2	_	7	
			1.8 ± 0.15		11	



11.4. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Output enable time	t _{PZL} ,t _{PZH} See Fig. 11.6., 11.7.1,	3.3 ± 0.3		7	ns	
		Table 11.6.1	2.5 ± 0.2		8	
			1.8 ± 0.15		12	
Output disable time	t_{PLZ}, t_{PHZ}	See Fig. 11.6., 11.7.1,	3.3 ± 0.3		7	ns
		Table 11.6.1	2.5 ± 0.2		8	
			1.8 ± 0.15		12	

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.

11.5. Capacitive Characteristics (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	V _{IN} = 0 V	3.0	4	pF
Switch terminal OFF-capacitance	C _{I/O}	$\overline{OE} = V_{CC}$, OE = GND, $V_{IS} = 0 \text{ V}$	3.0	3.5	pF
Switch terminal ON-capacitance	C _{I/O}	\overline{OE} = GND, OE = V _{CC} , V _{IS} = 0 V	3.0	7.5	pF

Note: Parameter guaranteed by design.



11.6. AC Test Circuits

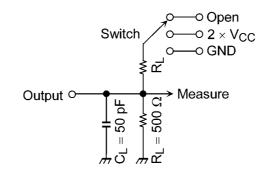


Table 11.6.1 Parameter for AC Test Circuit

Parameter	Switch
t_{PLZ} , t_{PZL}	$2 \times V_{CC}$
t _{PHZ} , t _{PZH}	GND

11.7. AC Waveform

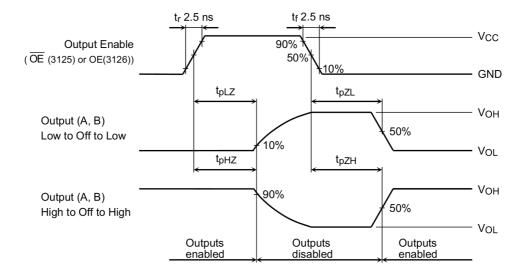


Fig. 11.7.1 AC Waveform tpLz, tpHz, tpzL, tpzH



12. Rise and Fall Time (t_r/t_f)

The $t_{r(out)}$ and $t_{f(out)}$ values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance ($C_{I/O}$) and the on-resistance (R_{ON}) of the input.

In practice, the $t_{r(out)}$ and $t_{f(out)}$ values are also affected by the circuit's capacitance and resistance components other than those of the TC7MBL3125CFT, TC7MBL3126CFT.

The $t_{r(out)}/t_{f(out)}$ values can be approximated as follows. (Fig. 12.1, Table 12.1 shows the calculation circuit.)

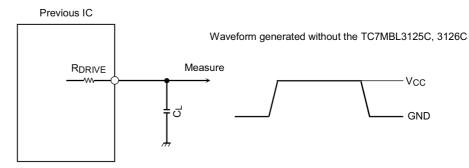
 $t_{r(out)}/t_{f(out)} \ (approx) = - \left(C_{L/O} + C_L \right) \ \cdot \ \left(R_{DRIVE} + R_{ON} \right) \ \cdot \ \ln \left(\left(\left(V_{OH} - V_{OL} \right) - V_M \right) / \left(V_{OH} - V_{OL} \right) \right)$ Where, R_{DRIVE} is the output impedance of the previous-stage circuit.

Calculation example:

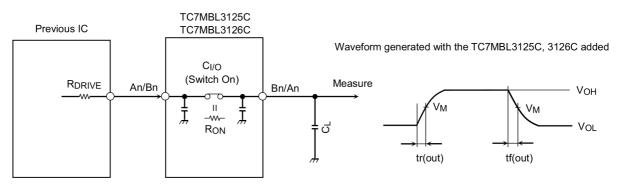
$$t_{r(out)}$$
 (approx) = - (7.5 + 15) E - 12 · (120 + 6.5) · ln (((3.0 - 0) - 1.5) / (3.0 - 0)) \approx 2.0 ns

Calculation conditions:

 V_{CC} = 3.0 V, C_L = 15 pF, R_{DRIVE} = 120 Ω (output impedance of the previous IC), V_M = 1.5 V (V_{CC} /2) Output of the previous IC = digital (i.e., high-level voltage = V_{CC} , low-level voltage = GND)



RDRIVE = output impedance of the previous IC



RDRIVE = output impedance of the previous IC

Fig. 12.1 Calculation Circuit

Table 12.1 Calculation Circuit

Characteristics	V_{CC} = 3.3 \pm 0.3 V	V_{CC} = 2.5 ± 0.2 V	V _{CC} = 1.8 ± 0.15 V
V_{M}	V _{CC} /2	V _{CC} /2	V _{CC} /2

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13. Characteristics Curves (Note)

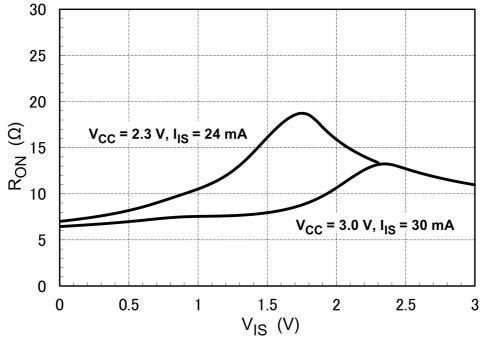


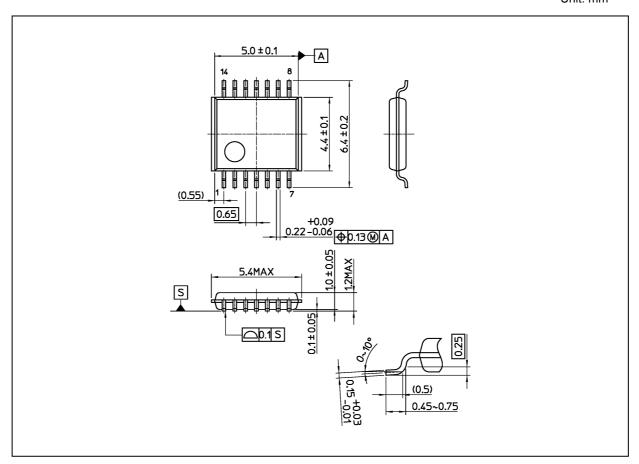
Fig. 13.1 R_{ON} - V_{IS} ($T_a = 25$ °C)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.06 g (typ.)

	Package Name(s)
Nickname: TSSOP14	



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